



FRACTIONAL-N PLL w/ INTEGRATED VCO 665 - 825, 1330 - 1650, 2660 - 3300 MHz

Features

- Tri-band RF Bandwidth: 665 - 825, 1330 - 1650, 2660 - 3300 MHz
- Ultra Low Phase Noise
 -105 dBc/Hz in Band Typ.
- Figure of Merit (FOM) -227 dBc/Hz
- < 180 fs RMS Jitter

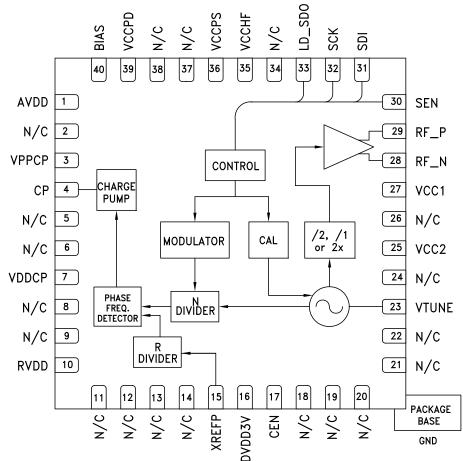
- 24-bit Step Size, Resolution 3 Hz typ
- Exact Frequency Mode
- · Built-in Digital Self Test
- 40 Lead 6x6 mm SMT Package: 36 mm²

Typical Applications

- · Cellular/4G Infrastructure
- · Repeaters and Femtocells
- · Communications Test Equipment
- CATV Equipment

- · Phased Array Applications
- · DDS Replacement
- · Very High Data Rate Radios

Functional Diagram







FRACTIONAL-N PLL w/ INTEGRATED VCO 665 - 825, 1330 - 1650, 2660 - 3300 MHz

General Description

The HMC822LP6CE is a fully functioned Fractional-N Phase-Locked-Loop (PLL) with an Integrated Voltage Controlled Oscillator (VCO). The PLL consists of an integrated low noise VCO with a tri-band output, an autocalibration subsystem for low voltage VCO tuning, a very low noise digital Phase Detector (PD), a precision controlled charge pump, a low noise reference path divider and a fractional divider.

The fractional PLL features an advanced delta-sigma modulator design that allows both ultra-fine step sizes and low spurious products. The phase detector (PD) features cycle slip prevention (CSP) technology to allow faster frequency hopping times. Ultra low in-close phase noise and low spurious also allows wider loop bandwidths for faster frequency hopping and low micro-phonics.

For theory of operation and register map refer to the "PLLs with Integrated VCOs - RF VCOs Operating Guide". To view the Operating Guide, please visit www.hittite.com and choose HMC822LP6CE from the "Search by Part Number" pull down menu.

Electrical Specifications, $T_A = +25^{\circ}$ C VPPCP, VDDCP, VCC1, VCC2 = 5V ±4%; RVDD, AVDD, DVDD3V, VCCPD, VCCHF, VCCPS = 3.3V ±6% GNDCP = GNDLS = Ground Paddle = 0V

Parameter	Condition	Min.	Тур.	Max.	Units
RF Output Characteristics					
VCO Frequency at PLL Input		1330		1650	MHz
RF Output Frequency at f _{VCO} /2		665		825	MHz
RF Output Frequency at f _{VCO}		1330		1650	MHz
RF Output Frequency at 2f _{VCO}		2660		3300	MHz
RF Output Power at f _{VCO} /2		9	11	13	dBm
RF Output Power at f _{VCO}		2.5	6.5	10.5	dBm
RF Output Power at 2f _{VCO}		-9	-4	1	dBm
VCO Tuning Sensitivity	Measured at fo, 2V		15		MHz/V
VCO Supply Pushing	Measured at fo, 2V	-2		1.5	MHz/V
RF Output fo/2 Harmonic	Doubler Mode		-22	-18	dBc
RF Output 3fo/2 Harmonic	Doubler Mode		-50	-41	dBc
RF Output 2nd Harmonic	fo/2/fo/2fo		-26 / -30 / -42	-22 / -19 / -36	dBc
RF Output 5fo/2 Harmonic	Doubler Mode		-60	-56	dBc
RF Output 3rd Harmonic	fo/2/fo/2fo		-27 / -40 / -60	-23 / -32 / -51	dBc
RF Output 7fo/2 Harmonic	Doubler Mode		-65	-61	dBc
RF Divider Characteristics					
19-Bit N-Divider Range (Integer)	Max = 2 ¹⁹ - 1			524,287	
19-Bit N-Divider Range (Fractional)	Fractional nominal divide ratio varies (-3 / +4) dynamically max			524,283	
REF Input Characteristics					
Max Ref Input Frequency	Synthesizer phase noise can degrade by about 5 dB when operating with a reference frequency near the low end of this range.	10	50	200	MHz
Ref Input Range	AC Coupled	1	2	3.3	Vpp
Ref Input Capacitance				5	pF
14-Bit R-Divider Range		1		16,383	





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Electrical Specifications (Continued)

Parameter	Condition	Min.	Тур.	Max.	Units
Phase Detector (PD)					
PD Frequency Fractional Feedback Mode	[1]	0.1		100	MHz
PD Frequency Fractional Feedforward Mode (and Register 6 [17:16] = 10)		0.1		80	MHz
PD Frequency Integer Mode	[1]	0.1		125	MHz
Charge Pump					•
Output Current		0.02		2.54	mA
Charge Pump Gain Step Size			20		μA
PD/Charge Pump SSB Phase Noise	50 MHz Ref, Input Referred				
1 kHz			-141		dBc/Hz
10 kHz	Add 1 dB for Fractional		-149		dBc/Hz
100 kHz	Add 3 dB for Fractional		-153		dBc/Hz
Logic Inputs					•
VIH Input High Voltage		DVDD3V-0.4		DVDD3V	V
VIL Input Low Voltage		0		0.4	V
Logic Outputs					•
VOH Output High Voltage		DVDD3V-0.4		DVDD3V	V
VOL Output Low Voltage		0		0.4	V
Power Supply Voltages					
Analog 3.3V Supplies	AVDD, VCCHF, VCCPS, VCCPD, RVDD	3.0	3.3	3.5	V
Digital Supply	DVDD3V	3.0	3.3	3.5	V
Analog 5V Supplies	VPPCP, VDDCP, VCC1, VCC2	4.8	5	5.2	V
Power Supply Currents					
+5V Analog Charge Pump	VPPCP, VDDCP		5.3		mA
+5V VCO Core and PLL Buffer	VCC2		56		mA
+5V VCO Divider and RF Buffer	VCC1		36		mA
+3.3V Analog	AVDD, VCCHF, VCCPS, VCCPD, RVDD		45		mA
+3.3V Digital	DVDD3V		6.5		mA
Power Down - Crystal Off	Reg 01h=0, Crystal Not Clocked		10		μА
Power Down - Crystal On, 100 MHz	Reg 01h=0, Crystal Clocked 100 MHz		10	200	μА
Power on Reset	•				
Typical Reset Voltage on DVDD			700		mV
Min DVDD Voltage for No Reset		1.5			V

Note 1: This maximum phase detector frequency can only be achieved if the minimum N value is respected. eg. In the case of fractional feedback mode, the maximum PFD rate = fvco/20 or 100 MHz, whichever is less.





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Electrical Specifications (Continued)

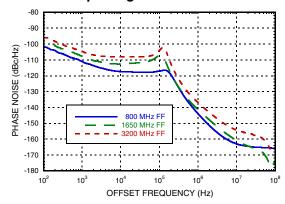
Parameter	Condition	Min.	Тур.	Max.	Units
VCO Open Loop Phase Noise at fo/2					
10 kHz Offset			-95	-89	dBc/Hz
100 kHz Offset			-124	-121	dBc/Hz
1 MHz Offset			-148	-145	dBc/Hz
10 MHz Offset			-162		dBc/Hz
100 MHz Offset			-163		dBc/Hz
VCO Open Loop Phase Noise at fo		•	•		
10 kHz Offset			-89	-83	dBc/Hz
100 kHz Offset			-118	-115	dBc/Hz
1 MHz Offset			-142	-139	dBc/Hz
10 MHz Offset			-162		dBc/Hz
100 MHz Offset			-164		dBc/Hz
VCO Open Loop Phase Noise at 2fo	•	,	'		
10 kHz Offset			-83	-83	dBc/Hz
100 kHz Offset			-112	-115	dBc/Hz
1 MHz Offset			-136	-139	dBc/Hz
10 MHz Offset			-155		dBc/Hz
100 MHz Offset			-160		dBc/Hz
Closed Loop Phase Noise PLL + VCO at fvo	co/2	,	'		
Integer, 25 MHz PD	1 kHz Offset		-113		dBc/Hz
Integer, 25 MHz PD	10 kHz Offset		-118		dBc/Hz
Integer, 25 MHz PD	100 kHz Offset		-118		dBc/Hz
Fractional, 25 MHz PD	1 kHz Offset		-109		dBc/Hz
Fractional, 25 MHz PD	10 kHz Offset		-111		dBc/Hz
Fractional, 25 MHz PD	100 kHz Offset		-116		dBc/Hz
Closed Loop Phase Noise PLL + VCO at fvo	00				•
Integer, 25 MHz PD	1 kHz Offset		-107		dBc/Hz
Integer, 25 MHz PD	10 kHz Offset		-112		dBc/Hz
Integer, 25 MHz PD	100 kHz Offset		-112		dBc/Hz
Fractional, 25 MHz PD	1 kHz Offset		-103		dBc/Hz
Fractional, 25 MHz PD	10 kHz Offset		-105		dBc/Hz
Fractional, 25 MHz PD	100 kHz Offset		-110		dBc/Hz
Closed Loop Phase Noise PLL + VCO at 2fe)	,	'		
Integer, 25 MHz PD	1 kHz Offset		-101		dBc/Hz
Integer, 25 MHz PD	10 kHz Offset		-106		dBc/Hz
Integer, 25 MHz PD	100 kHz Offset		-106		dBc/Hz
Fractional, 25 MHz PD	1 kHz Offset		-97		dBc/Hz
Fractional, 25 MHz PD	10 kHz Offset		-99		dBc/Hz
Fractional, 25 MHz PD	100 kHz Offset		-104		dBc/Hz
Figure of Merit	Normalized 1 Hz				
Integer Mode	Measured w/ 50 MHz PD at 30 kHz Offset		-229		dBc/Hz
Fractional Mode	Measured w/ 50 MHz PD at 30 kHz Offset		-227		dBc/Hz



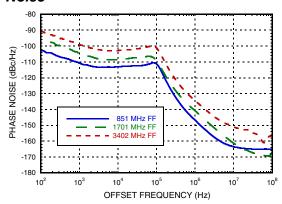


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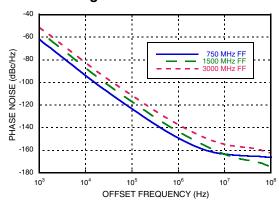
Closed Loop Integer Phase Noise



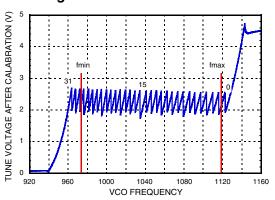
Typical Closed Loop Fractional Phase Noise [1]



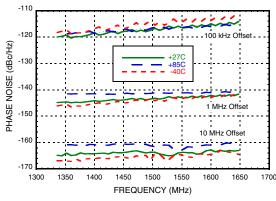
Free Running Phase Noise



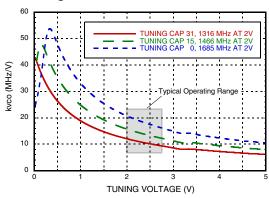
Typical VCO Sensitivity vs. Cap @ Fo Voltage



Free Running VCO Phase Noise Over Temperature



Typical VCO Sensitivity vs. Cap @ Fo Voltage



[1] Fractional Mode, 50 MHz Crystal, R=1, ~80 kHz Loop BW, (Loop filter values: Contact factory for component values) 2mA Charge Pump, -385μA Offset.





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Typical Output Power - Narrow Band Match

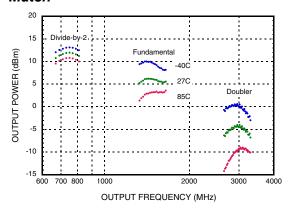
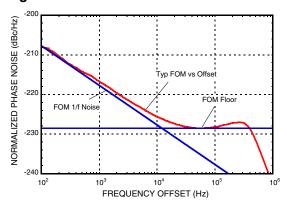


Figure of Merit







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Pin Descriptions

Pin Number	Function	Description	
1	AVDD	DC Power Supply for analog circuitry.	
2, 5, 6, 8, 9, 11 - 14, 18 - 22, 24, 26, 34, 37, 38	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	VPPCP	Power Supply for charge pump analog section	
4	СР	Charge Pump Output	
7	VDDCP	Power Supply for the charge pump digital section	
10	RVDD	Reference Supply	
15	XREFP	Reference Oscillator Input	
16	DVDD3V	DC Power Supply for Digital (CMOS) Circuitry	
17	CEN	Chip Enable. Connect to logic high for normal operation.	
23	VTUNE	VCO Varactor. Tuning Port Input.	
25	VCC2	VCO Analog Supply 2	
27	VCC1	VCO Analog Supply 1	
28	RF_N ^[1]	RF Positive Output	
29	RF_P ^[1]	RF Negative Output	
30	SEN	PLL Serial Port Enable (CMOS) Logic Input	
31	SDI	PLL Serial Port Data (CMOS) Logic Input	
32	SCK	PLL Serial Port Clock (CMOS) Logic Input	
33	LD_SDO	Lock Detect, or Serial Data, or General Purpose (CMOS) Logic Output (GPO)	
35	VCCHF	DC Power Supply for Analog Circuitry	
36	VCCPS	DC Power Supply for Analog Prescaler	
39	VCCPD	DC Power Supply for Phase Detector	
40	BIAS	External bypass decoupling for precision bias circuits. Note: 1.920V \pm 20mV reference voltage (BIAS) is generated internally and cannot drive an external load. Must be measured with 10G Ω meter such as Agilent 34410A, normal 10M Ω DVM will read erroneously.	

^[1] For doubler mode of operation, pin 28 (RF_N) and pin 29 (RF_P) outputs must be shorted together.





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Absolute Maximum Ratings

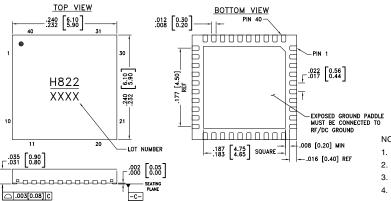
-0.3V to +3.6V
-0.3V to +5.5V
-0.3V to +5.5V
-40°C to +85°C
-65°C to 150°C
150 °C
9 °C/W
260°C
40 sec
Class 1B

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Recomended Operating Conditions

Parameter	Condition	Min.	Тур.	Max.	Units	
Temperature						
Junction Temperature				125	°C	
Ambient Temperature		-40		85	°C	
Supply Voltage						
AVDD, RVDD, DVDD3V, VCCPD, VCCHF, VCCPS		3.0	3.3	3.5	V	
VPPCP, VDDCP, VCC1, VCC2		4.8	5	5.2	V	

Outline Drawing



NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 3 I FAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [1]
HMC822LP6CE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	H822 XXXX

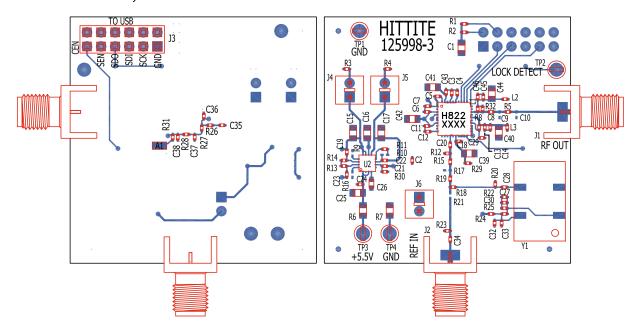
[1] 4-Digit lot number XXXX





FRACTIONAL-N PLL w/ INTEGRATED VCO 665 - 825, 1330 - 1650, 2660 - 3300 MHz

Evaluation PCB, fo & fo/2 Modes



The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Evaluation PCB Schematic

To view this Evaluation PCB Schematic please visit www.hittite.com and choose HMC822LP6CE from the "Search by Part Number" pull down menu to view the product splash page.





FRACTIONAL-N PLL w/ INTEGRATED VCO 665 - 825, 1330 - 1650, 2660 - 3300 MHz

List of Materials for Evaluation PCB 127827, fo & fo/2 Mode [1]

Item	Description		
J1, J2	PCB Mount SMA RF Connector		
J3	Dual Row Terminal Strip		
J4 - J6	Connector Header		
C1, C15 - C17, C25	10 μF Capacitor, 0805 Pkg.		
C2, C3, C6, C7, C11, C12, C14, C18, C27, C43, C45	0.47 μF Capacitor, 0402 Pkg.		
C4, C13	22 pF Capacitor, 0402 Pkg.		
C5, C33	1000 pF Capacitor, 0402 Pkg.		
C8	1.5 pF Capacitor, 0402 Pkg.		
C19 - C24, C28, C30, C32, C34	0.1 μF Capacitor, 0402 Pkg.		
C26	1 μF Capacitor, 0603 Pkg.		
C29	47 pF Capacitor, 0402 Pkg.		
C35	3300 pF Capacitor, 0402 Pkg.		
C36	270 pF Capacitor, 0402 Pkg.		
C37, C38	68 pF Capacitor, 0402 Pkg.		
C39 - C42, C44	4.7 μF Tantalum Capacitor, 0805 Pkg		
R1, R2, R5, R8, R11, R15, R18, R19, R21, R24	0 Ohm Resistor, 0402 Pkg.		
R3, R4	1 Ohm Resistor, 0402 Pkg.		
R6, R7	0 Ohm Resistor, 0805 Pkg.		
R12, R20, R29	51 Ohm Resistor, 0402 Pkg.		
R22, R25	20 kOhm Resistor, 0402 Pkg.		
R26 - R28	1k Ohm Resistor, 0402 Pkg.		
L1	8.2 nH Inductor, 0402 Pkg.		
L2, L3	47 nH Inductor, 0402 Pkg.		
TP3, TP4 Test Point PC Compact SMT			
U1	HMC822LP6CE PLL with Integrated VCO		
U2	HMC860LP3E Low Noise Quad Linear Regulator		
Y1	3.3V, 50 MHz VCXO Crystal Oscillator		
PCB [2]	125998 Evaluation Board		

^[1] Reference this number when ordering complete evaluation PCB

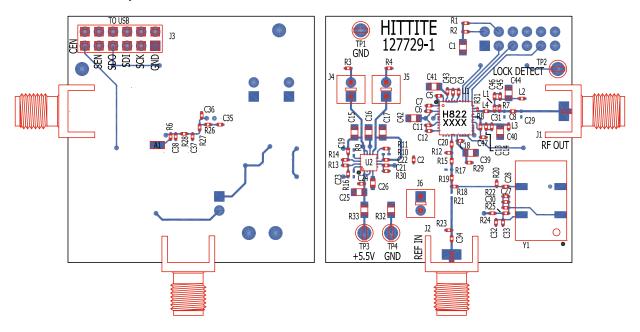
^[2] Circuit Board Material: Rogers 4350 or Arlon 25FR and FR4





FRACTIONAL-N PLL w/ INTEGRATED VCO 665 - 825, 1330 - 1650, 2660 - 3300 MHz

Evaluation PCB, 2xfo Mode



The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Evaluation PCB Schematic

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FRACTIONAL-N PLL w/ INTEGRATED VCO 665 - 825, 1330 - 1650, 2660 - 3300 MHz

List of Materials for Evaluation PCB 128159, 2xfo Mode [1]

Item	Description		
J1, J2	PCB Mount SMA RF Connector		
J3	Dual Row Terminal Strip		
J4 - J6	Connector Header		
C1, C15 - C17, C25	10 μF Capacitor, 0805 Pkg.		
C2, C3, C6, C12, C14, C18, C27, C43, C45	0.47 μF Capacitor, 0402 Pkg.		
C4, C13	22 pF Capacitor, 0402 Pkg.		
C5, C33	1000 pF Capacitor, 0402 Pkg.		
C7, C11	470 nF Capacitor, 0402 Pkg.		
C8	8.2 pF Capacitor, 0402 Pkg.		
C19 - C24, C28, C30, C32, C34	0.1 μF Capacitor, 0402 Pkg.		
C26	1 μF Capacitor, 0603 Pkg.		
C29	1 pF Capacitor, 0402 Pkg.		
C31	0.5 pF Capacitor, 0402 Pkg.		
C35	3300 pF Capacitor, 0402 Pkg.		
C36	270 pF Capacitor, 0402 Pkg.		
C37, C38	68 pF Capacitor, 0402 Pkg.		
C39 - C42, C44	4.7 μF Tantalum Capacitor, 0805 Pkg		
C46	27 pF Capacitor, 0402 Pkg.		
C47	47 pF Capacitor, 0402 Pkg.		
R1, R2, R8, R11, R15, R18, R19, R21, R24	0 Ohm Resistor, 0402 Pkg.		
R3, R4	1 Ohm Resistor, 0402 Pkg.		
R12, R20, R23, R29	51 Ohm Resistor, 0402 Pkg.		
R13, R14, R30	220 kOhm Resistor, 0402 Pkg.		
R22, R25	20 kOhm Resistor, 0402 Pkg.		
R26 - R28	1 kOhm Resistor, 0402 Pkg.		
R31	0 Ohm Resistor, 0201 Pkg.		
R32, R33	0 Ohm Resistor, 0805 Pkg.		
L1	10 nH Inductor, 0402 Pkg.		
L2, L3	47 nH Inductor, 0402 Pkg.		
L4	1.8 nH Inductor, 0402 Pkg.		
TP1 - TP4	Test Point PC Compact SMT		
U1	HMC822LP6CE PLL with Integrated VCO		
U2	HMC860LP3E Low Noise Quad Linear Regulator		
Y1	3.3V, 50 MHz VCXO Crystal Oscillator		

^[1] Reference this number when ordering complete evaluation PCB

^[2] Circuit Board Material: Rogers 4350 or Arlon 25FR and FR4

ПОСТАВКА ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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